

# SBL20L15C/FC

## Power Schottky Rectifier - 20Amp 15Volt

#### □ Features

- -Plastic package has Underwriters Laboratory Flammability Classifications 94V-0
- -Optimized for OR-ing applications
- -Ultra low forward voltage, high current capability
- -High surge capacity
- -Ultra low power loss, high efficiency

#### Application

- -For the OR-ing of Parallel Power Supplies
- -Solar-System Control Box

#### ☐ Absolute maximum ratings

Symbol	Ratings	Unit	Conditions	
<b>I</b> F(AV)	20	Α	Average Forward Current	
VRRM	15	V	Repetitive Peak Reverse Voltage	
IFSM	150	Α	Peak Forward Surge Current	
VF	0.31	V	Forward Voltage Drop	
Tj , Tstg	-50 to +125	°C	Operating and Storage Temperature	

### Electrical characteristics

Parameters	Symbol	Ratings	Conditions
			Per Leg at IF = 20A
Maximum Instantaneous Forward Voltage	VF	0.41V	Tc = 25°C
		0.31V	Tc = 125°C
			Per Leg at VR = 15V
Maximum Reverse Leakage Current	lr	15.0mA	Tc = 25°C
		500mA	Tc = 125°C
Maximum Voltage Rate of Change	dv/dt	10,000 V/μs	Rated VR
			Per Leg
Typical Thermal Resistance, Junction to Case	Rθ (j-c)	2.2 °C/W	TO-220AC
		4.5 °C/W	ITO-220AC

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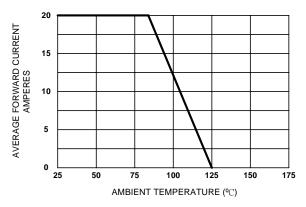


Figure 1. Forward Current Derating Curve

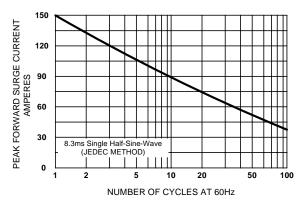


Figure 2. Maximum Non-repetitive Surge Current

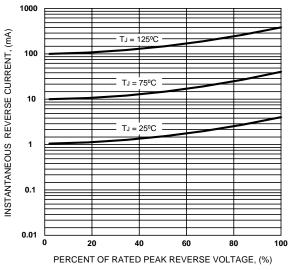


Figure 3. Typical Reverse Characteristics

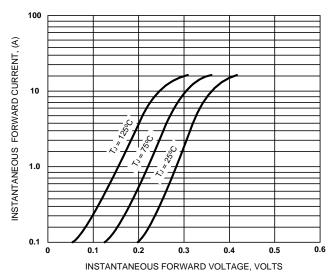


Figure 4. Typical Forward Characteristics

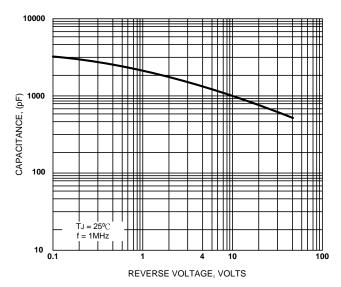
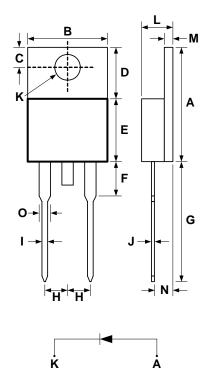


Figure 5. Typical Junction Capacitance

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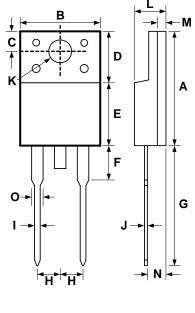
### **TO-220AC**



DIMENSIONS						
1 1						
DIM	INCHES		MM		NOTE	
	MIN	MAX	MIN	MAX	NOTE	
Α	.579	.606	14.70	15.40		
В	.392	.411	9.95	10.45		
С	.104	.116	2.65	2.95		
D	.248	.272	6.30	6.90		
Е	.325	.350	8.25	8.90		
F	.126	.157	3.20	4.00		
G	.492	.551	12.50	14.00		
Н	.096	.108	2.45	2.75		
I	.028	.039	0.70	1.00		
J	.010	.022	0.25	0.55		
K	.146	.157	3.70	4.00		
L	.167	.187	4.25	4.75		
М	.045	.057	1.15	1.45		
N	.089	.114	2.25	2.90		
0	.047	.055	1.20	1.40		

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### ITO-220AC





DIMENSIONS						
DIM	INCHES		MM		NOTE	
	MIN	MAX	MIN	MAX	NOTE	
Α	.577	.640	14.65	16.25		
В	.386	.406	9.80	10.30		
С	.098	.114	2.50	2.90		
D	.258	.274	6.55	6.95		
Е	.315	.331	8.00	8.40		
F	.079	.161	2.00	4.10		
G	.492	.571	12.50	14.50		
Н	.089	.106	2.25	2.70		
ı	.024	.035	0.60	0.90		
J	.020	.028	0.50	0.70		
K	.120	.138	3.05	3.50		
L	.169	.189	4.30	4.80		
М	.031	.063	0.80	1.60		
N	.079	.112	2.00	2.85		
0	.043	.055	1.10	1.40		



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